

扩展功能

## Si-TaSi<sub>2</sub>共晶自生复合场发射材料的定向凝固组织特征

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**摘要** 采用电子束悬浮区熔装置(EBFZM)制备了Si-TaSi<sub>2</sub>共晶自生复合场发射材料, 系统地研究了Si-TaSi<sub>2</sub>共晶的定向凝固组织特征。当凝固速率在0.3~9.0mm/min范围内变化时, 均可获得Si-TaSi<sub>2</sub>共晶自生复合材料, 具有高精确取向的TaSi<sub>2</sub>纤维在硅连续基体中均匀分布。随着凝固速率的增大, TaSi<sub>2</sub>纤维的直径和平均间距减小, 面密度和体积分数增大。采用零功率法考察了不同凝固速率时的固-液界面形貌。当凝固速率由0.3mm/min变化到5.0mm/min时, 固-液界面经历了平界面→浅胞状界面→胞状界面→平界面的演化过程。

**关键词** 定向凝固 电子束悬浮区熔 Si-TaSi<sub>2</sub>共晶自生复合材料 固-液界面

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## Microstructures of Directionally Solidified Si-TaSi<sub>2</sub> Eutectic *in situ* Composite for Field Emission

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**Abstract** The directionally solidified Si-TaSi<sub>2</sub> eutectic in ~situ composite for field emission was prepared with the electron beam floating zone melting (EBFZM) technique. The microstructure characteristic of Si-TaSi<sub>2</sub> eutectic was systematically investigated. The Si-TaSi<sub>2</sub> eutectic in ~situ composite, which has high-aligned and uniformly-distributed TaSi<sub>2</sub> fibers in the Si matrix, can be obtained when the solidification rate changes from 0.3mm/min to 9.0mm/min. With the increase of the solidification rate, the diameter and the inter-rod spacing of the TaSi<sub>2</sub> fibers are decreased, while the density and the volume fraction of the fibers are increased. The solid/liquid interface is studied by the zero power method as well. When the solidification rate varies from 0.3mm/min to 5.0 mm/min, the solid/liquid interface morphology has the following evolution processing: planar interface→shallow cell interface→cell interface→planar interface.

## Key words

directional solidification electron beam floating zone melting Si-TaSi<sub>2</sub> eutectic *in situ* composite solid/liquid interface

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